

Engineering self-assembled SiGe islands for robust electron confinement in Si (<i>4 pages</i>)	153306
R. O. Rezaev, S. Kiravittaya, V. M. Fomin, A. Rastelli, and O. G. Schmidt	
Surface physics, nanoscale physics, low-dimensional systems	
Characterization of structural dynamics of VO ₂ thin film on <i>c</i> -Al ₂ O ₃ using in-air time-resolved x-ray diffraction (<i>4 pages</i>)	153401
Masaki Hada, Kunio Okimura, and Jiro Matsuo	
Mimicking nanoribbon behavior using a graphene layer on SiC (<i>4 pages</i>)	153402
Matheus P. Lima, A. R. Rocha, Antônio J. R. da Silva, and A. Fazzio	
Mechanochemistry in Cu nanowires: N and N ₂ enhancing the atomic chain formation (<i>4 pages</i>)	153403
E. P. M. Amorim and E. Z. da Silva	
Simulation of hydrogenated graphene field-effect transistors through a multiscale approach (<i>4 pages</i>)	153404
G. Fiori, S. Lebègue, A. Betti, P. Michetti, M. Klintonberg, O. Eriksson, and G. Iannaccone	
Evaluation of the Green's function of disordered graphene (<i>4 pages</i>)	153405
W. Zhu, Q. W. Shi, X. R. Wang, X. P. Wang, J. L. Yang, J. Chen, and J. G. Hou	
Mean-field quantum phase transition in graphene and in general gapless systems (<i>4 pages</i>)	153406
Ádám Bácsi, Attila Virosztek, László Borda, and Balázs Dóra	
Absence of rippling in graphene under biaxial tensile strain (<i>4 pages</i>)	153407
Bipul Rakshit and Priya Mahadevan	
First-principles study of epitaxial strain as a method of B4→BCT stabilization in ZnO, ZnS, and CdS (<i>4 pages</i>)	153408
Benjamin J. Morgan	
Structural and electronic stability of a volleyball-shaped B ₈₀ fullerene (<i>4 pages</i>)	153409
Xiao-Qian Wang	
X-ray edge singularity of bilayer graphene (<i>4 pages</i>)	153410
Hyun C. Lee	
Graded index surface-plasmon-polariton devices for subwavelength light management (<i>4 pages</i>)	153411
G. Della Valle and S. Longhi	
Comparative van der Waals density-functional study of graphene on metal surfaces (<i>4 pages</i>)	153412
Ikutaro Hamada and Minoru Otani	
Quantum confinement, core level shifts, and dopant segregation in P-doped Si(110) nanowires (<i>4 pages</i>)	153413
Jiaxin Han, Tzu-Liang Chan, and James R. Chelikowsky	
Edge states propagating from a defect of graphite: Scanning tunneling spectroscopy measurements (<i>4 pages</i>)	153414
Takahiro Kondo, Yujiro Honma, Junepyo Oh, Takahiro Machida, and Junji Nakamura	

ARTICLES

Electronic structure and strongly correlated systems

Momentum-space anisotropy and pseudogaps: A comparative cluster dynamical mean-field analysis of the doping-driven metal-insulator transition in the two-dimensional Hubbard model (<i>14 pages</i>)	155101
E. Gull, M. Ferrero, O. Parcollet, A. Georges, and A. J. Millis	

(Continued)